## NSN 5961-01-521-1582



Semiconductor Device Set - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-521-1582 **Inclosure Material:** Metal all transistor **Overall Height:** 0.350 inches all transistor **Overall Diameter:** 0.875 inches all transistor **Function For Which Designed: Amplifier Mounting Facility Quantity:** 2 all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 180.0 collector to base voltage/static/emitter open all transistor **Current Rating Per Characteristic:** 16.00 amperes zero-gate-voltage source current blank all transistor **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction all transistor **Terminal Type And Quantity:** 2 pin all transistor Shelf Life:

N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0